It's often the case that the force responsible for this motion is the Loventz force,

f = Florente = E+VXB

And typically v'&B' are small enough where only E' really affects the charges \* (more later)

So, プー・ナー・「E+VxB)でのE

this is Ohm's Law, which is really a model that many materials seem to be able to be noteted by.

Note: F=ma does not imply an increasing current even Hough Jav (nemember Hus?)

If they were no damping (collision, thermal lossies), it would. But elections in real naturals are The a gas, they have large random V's depending on temperatue. So applying a (small) force couses a drift, but the collisions tend to still randomize the motion (called thermalitation).

-) think of the drag force of terminal velocity

> Thermal is by , but Vortet is small

So the current depends on that drift relocity

J= ng Verift J called the Dude model

(hoventz averaging)

memumber?

met effect is
a cornent to the right. TE 7

Comment: or depends on the maximal

Materials ul large conductivity are good conductors. (you only need a small force to get a large flow)

- Copper is used in most household using  $\frac{C_{\text{cu}} \simeq 6.10^{7} \frac{e/s \cdot m^{2}}{N/c} = \frac{c^{2}s}{k_{5}m^{3}} = \frac{1}{0 h_{m} m} = \frac{1}{n m}$ 

- This is a huge conductivity. By contrast, Wood (an insulator) has Twood ~ 10 to 10 7m

- A nesistor in a circuit would be more like 10+3 or 10+ I'm ('mid range")

Comment: I thought E=0 in metals!

For static situations, yes that's time, J= OE so if J=0 then E=0.

For a metal T is very large (0->00), so that E= T/ >0 even if there's finite coment.

That is, very small \( \vec{E}\) fields are needed to drive corrects in neetals. and in our approximation that \( \sigma \to \ightarrow \ightar

timal Comment. As there are Collisions and thermal losses when driving current. The power dissipated in the system must he P = DV I = work change second

Phy 482 Ohnis Law (4) Example: Uniform Conducting Wine Here's a bit of wine, We can use Chin's anea ( Law, A ) I ) Law, F= 0 E high EDV > low to find 184's Ohm's. the current density is uniterin: J= T/A \* here the electric field is also muitorm: E=

(\* we will come back to this)

SO,  $\frac{\Gamma}{A} = \sigma \frac{\Delta V}{L} \Rightarrow \Delta V = \frac{\Gamma}{\sigma A} \Gamma$ We can call  $\frac{L}{\sigma A} = R$  the resistance of the material

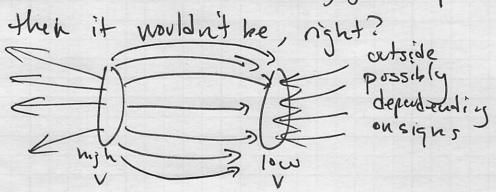
R depends on the geametry and the resistivity of the Material. In this case,

R= = p = where p= /o (nemember) [R] = Ohms = [R] so DV = RI (like 184)

Real wines have small E-fields in them and thus small DVs. They are negovable, too! But, big DV's occur across resistance elements; hence, we often focus on them!



Phy 482 Ohnis Law (5) In the previous example, why was Euniform? If there was no materal, just two plates,



The cylindrical conductor charges things the current can't leave the conductor for free space, hence I is confued to the Conductor, thus == J/o is as well. \* ( this Tsu't the full stony either! It's

the E responsible for F that doesn't leave, but the changes generating that E produce external fields!) " will comeback to this!

E must be parallel to the edges! Ein=0 Emust be parallel to the edges. The edges. The character of the sis in steady state; when the "switch" is closed changes quickly accumulate to make this E.)

This E.)

This is in steady state; when the "switch" is closed change of surface change accumulate to shape the field!

Another explanation, the field!

The ED I Deplaces Equ is satisfied in steady state.

 $V = V_0(1 - \frac{x}{L})$  solves this w/dV/dn = 0Uniqueness granuntees that  $\vec{E} = -\nabla V = \frac{+V_0}{L}\hat{x}$ 

Phy 482 Ohnis Law (6) Groing hack to consenation of current,

of + ToJ=0 is a local statement

that is, it holds in the bulk constacting

and outside but might have different

på & Fé depending on whene you are.

In the bulk, in steady state, do/dt =0 the distribution of charge is (roughly) uncharged even though charges are moving!

So,  $\nabla \circ \vec{J} = 0$  again locally (at every pt.)

Berause  $\overrightarrow{J} = \overrightarrow{\sigma} \overrightarrow{E}$  in the bulk,  $\overrightarrow{\nabla} \cdot \overrightarrow{E} = \overrightarrow{O}$  (thus,  $\overrightarrow{\nabla}^2 V = O$  haplace's equ can change then finny shaped resistors will have

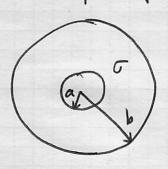
V· E=0 and E·n=0 at the edges.

Charge built up on the surface to shape the field.



## Example: Two Concentric spheres

Two sphenes (radii a + b, b>a) are constructed So the larger one contains the smallerone. There is a material of conductivity, or, between them. A potential of V is maintained between them with the smaller splene at higher potential. What's I?



Assume they are metal Spheres so that any charges are on the surfaces.

Can also assure & distributed over the sphere inside the larger one as long as we Solve for Q interms of

Solve for Q interprete known variables.

$$E = \frac{Q}{41160} \frac{1}{r^2} \hat{r}$$
So that,

the total current (in terms of Q) is,

$$I = \int \vec{J} \cdot d\vec{a} = \sigma \int \vec{E} \cdot d\vec{a} = \sigma \cdot \vec{G} = Gauss$$

$$Law$$

We need to relate this to V So we compute the potential ketnear the spheres.

Phy 482 | Ohm's Law (8)

$$V = -\int_{a}^{b} \vec{E} \cdot d\vec{l} = \frac{Q}{4\pi\epsilon_{0}} \left(\frac{1}{b} - \frac{1}{a}\right) < O \text{ right?}$$
 $= \frac{Q}{4\pi\epsilon_{0}} \left(\frac{a-b}{ab}\right) < O \text{ b>a neumber?}$ 

So with  $\vec{L} = \sigma \frac{Q}{\epsilon_{0}}$  and  $\vec{V} = \frac{Q}{4\pi\epsilon_{0}} \frac{(a-b)}{ab}$ ,

 $\vec{V} = \frac{(\epsilon_{0}\vec{L}/\sigma)}{4\pi\epsilon_{0}} \frac{(a-b)}{ab} = \vec{L} \left(\frac{1}{4\pi\sigma}\right) \frac{(a-b)}{ab}$ 

or  $\vec{V} = \vec{L} \frac{Q}{4\pi} \left(\frac{a-b}{ab}\right) = \vec{L} R$  so

 $\vec{R} = \frac{P}{4\pi} \left(\frac{a-b}{ab}\right)$  and depends only on geometry  $(a,b)$  d.  $\vec{P}$ .